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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/657,586	09/08/2003	Bantval Jayant Baliga	9236-6DV 9878	
20792 75	90 06/17/2005		EXAMINER	
MYERS BIGEL SIBLEY & SAJOVEC			TRAN, BINH X	
PO BOX 37428				
RALEIGH, NC 27627			ART UNIT	PAPER NUMBER
,			1765	

DATE MAILED: 06/17/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

•	Application No.	Applicant(s)			
	10/657,586	BALIGA, BANTVAL JAYANT			
Office Action Summary	Examiner	Art Unit			
	Binh X. Tran	1765			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period we Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
 Responsive to communication(s) filed on <u>08 September 2003</u>. This action is FINAL. 2b) This action is non-final. Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i>, 1935 C.D. 11, 453 O.G. 213. 					
Disposition of Claims					
 4) Claim(s) 1-6 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) 5 and 6 is/are allowed. 6) Claim(s) 1-3 is/are rejected. 7) Claim(s) 4 is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement. 					
Application Papers					
9)⊠ The specification is objected to by the Examiner 10)⊠ The drawing(s) filed on <u>08 September 2003</u> is/a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction 11)□ The oath or declaration is objected to by the Examiner 11.	re: a) accepted or b) objected or b)	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 					
Attachment(s) 1) ☑ Notice of References Cited (PTO-892) 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) ☑ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 9/8/2003.	4) Interview Summary (Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:	•			

DETAILED ACTION

Specification

1. The disclosure is objected to because of the following informalities: In the "Reference to Priority Application", after the phrase, "This application is a divisional of US Application Serial No. 09/992,104, filed November 5, 2001", the examiner suggests applicants to insert --now, US Patent 6,649,975--.

Appropriate correction is required.

2. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.

Claim Objections

3. Claim 1, 3-4 are objected to because of the following informalities:

In claim 1 and 3, the examiner suggests the applicants to spell out what specific term that the abbreviation "UMOSFET" stands for.

In claim 4, the examiner suggests the applicants to spell out what specific term that the abbreviation "MOSFET" stands for

Appropriate correction is required.

Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

5. Claims 1-3 are rejected under 35 U.S.C. 102(e) as being anticipated by Singh et al. (US 6,121,633).

Respect to claim 1, Singh discloses a method for forming a vertical power device comprising the steps of:

forming a first and second deep trench (16) n a semiconductor substrate having a drift region (14) of the first conductivity type therein (i.e. p-type) that extends into the mesa defined between first and second opposing sidewalls of the first and second deep trenches, respectively (Fig 2-3, col. 10 lines 18-55; col. 11 lines 63 to col. 12 line 10); forming a UMOSFET in the mesa (col. 5 lines 15-25).

Respect to claim 2, Singh discloses the step of forming a first and second base shield region (18) of second conductivity type (n-type) that extend into the mesa and are self-aligned with the first and second opposing side walls (Fig 2-3, col. 10 lines 35-42). Respect to claim 3, Singh discloses the step of forming a transition region (22) of the first conductivity type (p-type) that extends between the drift region (14) and a base region of the second conductivity type (n-type) with the UMOSFET (Fig 2-3, col. 19-29).

Allowable Subject Matter

6. Claim 4 would be allowable if rewritten or amended to overcome the objection set forth in this Office action.

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7. Claims 5-6 are allowed.

8. The following is a statement of reasons for the indication of allowable subject matter: The cited prior arts fail to disclose or suggest either one the following step in conjunction with all other limitations the claim: forming a source electrode that electrically connects the first and second insulated source electrodes, the source region and the base region together; or forming a source electrode that extends on the first face and is electrically connected to said first and second insulated electrodes and to said first and second source regions.

Conclusion

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Binh X. Tran whose telephone number is (571) 272-1469. The examiner can normally be reached on Monday-Thursday and every other Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on (571) 272-1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

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you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

BinhTran

Binh X. Tran